



PJQ4548P-AU

40V N-Channel Enhancement Mode MOSFET

Voltage **40 V** **Current** **43 A**

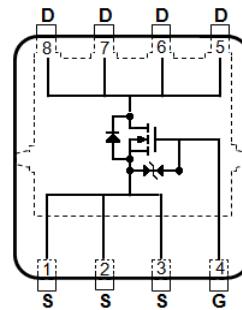
Features

- $R_{DS(ON)}$, $V_{GS} @ 10V$, $I_D @ 10A < 9.1m\Omega$
- $R_{DS(ON)}$, $V_{GS} @ 4.5V$, $I_D @ 6A < 12.5m\Omega$
- Excellent FOM
- Logic Level Drive
- AEC-Q101 qualified
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

- Case : DFN3333-8L Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight : 0.03 grams

DFN3333-8L



Maximum Ratings and Thermal Characteristics ($T_A=25^\circ C$ unless otherwise noted)

PARAMETER	SYMBOL	LIMIT	UNITS
Drain-Source Voltage	V_{DS}	40	V
Gate-Source Voltage	V_{GS}	± 20	
Continuous Drain Current ^(Note 3)	I_D	43	A
$T_C=100^\circ C$		30	
Pulsed Drain Current ^(Note 1)	I_{DM}	172	
Power Dissipation	P_D	30	W
$T_C=100^\circ C$		15	
Continuous Drain Current ^(Note 4)	I_D	12.4	A
$T_A=70^\circ C$		10.3	
Power Dissipation	P_D	2.5	W
$T_A=70^\circ C$		1.8	
Single Pulse Avalanche Energy ^(Note 5)	E_{AS}	42	mJ
Operating Junction and Storage Temperature Range	T_J, T_{STG}	-55~175	°C
Thermal Resistance ^(Note 4)	Junction to Case	$R_{\theta JC}$	5
	Junction to Ambient	$R_{\theta JA}$	60



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Electrical Characteristics ($T_A=25^\circ C$ unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV_{DSS}	$V_{GS}=0V, I_D=250\mu A$	40	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=50\mu A$	1.1	1.6	2.3	
Drain-Source On-State Resistance	$R_{DS(on)}$	$V_{GS}=10V, I_D=10A$	-	7.3	9.1	$m\Omega$
		$V_{GS}=4.5V, I_D=6A$	-	9.6	12.5	
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=40V, V_{GS}=0V$	-	-	1	μA
Gate-Source Leakage Current	I_{GSS}	$V_{GS}=\pm 20V, V_{DS}=0V$	-	-	± 10	μA
		$V_{GS}=\pm 10V, V_{DS}=0V$	-	-	± 1	
Dynamic ^(Note 6)						
Total Gate Charge	Q_g	$V_{DS}=32V, I_D=10A,$ $V_{GS}=10V$	-	13	-	nC
Gate-Source Charge	Q_{gs}		-	3	-	
Gate-Drain Charge	Q_{gd}		-	2	-	
Input Capacitance	C_{iss}	$V_{DS}=25V, V_{GS}=0V,$ $f=1MHz$	-	778	-	pF
Output Capacitance	C_{oss}		-	180	-	
Reverse Transfer Capacitance	C_{rss}		-	25	-	
Gate resistance	R_g	$f=1MHz$	-	1.6	-	Ω
Turn-On Delay Time	$t_{d(on)}$	$V_{DS}=32V, I_D=10A,$ $V_{GS}=10V, R_G=3\Omega$ (Note 2)	-	9	-	ns
Turn-On Rise Time	t_r		-	3	-	
Turn-Off Delay Time	$t_{d(off)}$		-	21	-	
Turn-Off Fall Time	t_f		-	3	-	
Drain-Source Diode						
Diode Forward Current	I_s	$T_C=25^\circ C$	-	-	43	A
Pulsed Diode Forward Current	I_{SM}		-	-	172	
Diode Forward Voltage	V_{SD}	$I_s=20A, V_{GS}=0V$	-	0.9	1.3	V
Reverse Recovery Time	T_{rr}	$V_{GS}=0V, I_s=20A$ $dI_s/dt=100A/\mu s$	-	21	-	ns
Reverse Recovery Charge	Q_{rr}		-	10	-	

NOTES :

1. Pulse width $\leq 100\mu s$, Duty cycle $\leq 2\%$.
2. Essentially independent of operating temperature typical characteristics.
3. Chip capability with an $R_{eJC}=5^\circ C/W$.
4. R_{eJA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
5. The test condition is $L=0.5mH, I_{AS}=13A, V_{DD}=30V, V_{GS}=10V$, Starting $T_J=25^\circ C$.
6. Guaranteed by design, not subject to production testing.



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TYPICAL CHARACTERISTIC CURVES

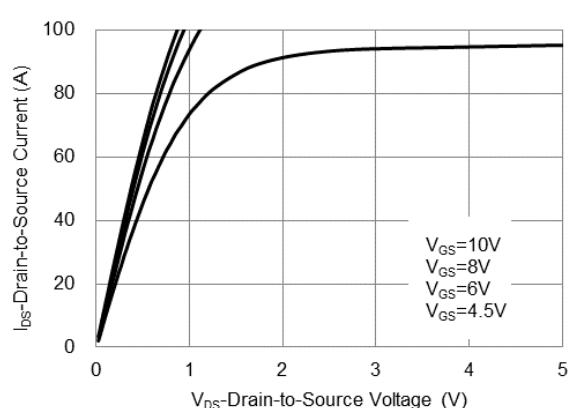


Fig.1 On-Region Characteristics

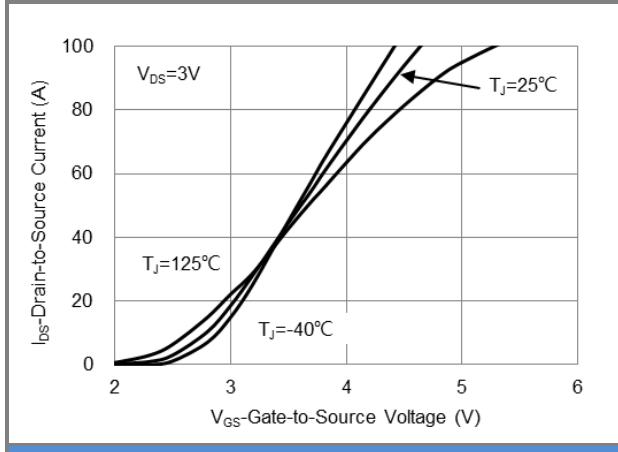


Fig.2 Transfer Characteristics

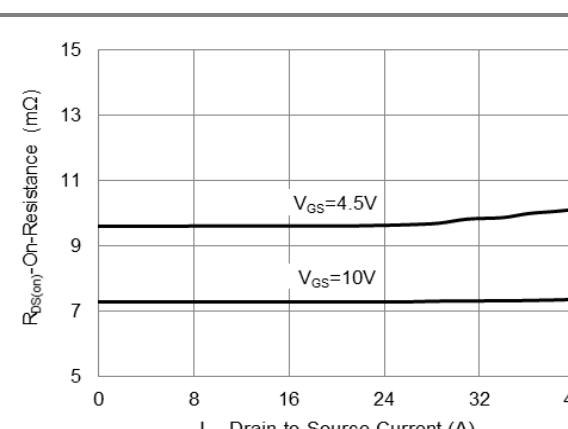


Fig.3 On-Resistance vs. Drain Current

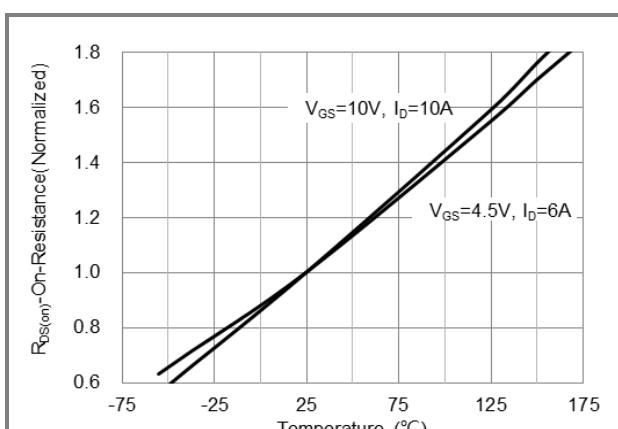


Fig.4 On-Resistance vs. Junction temperature

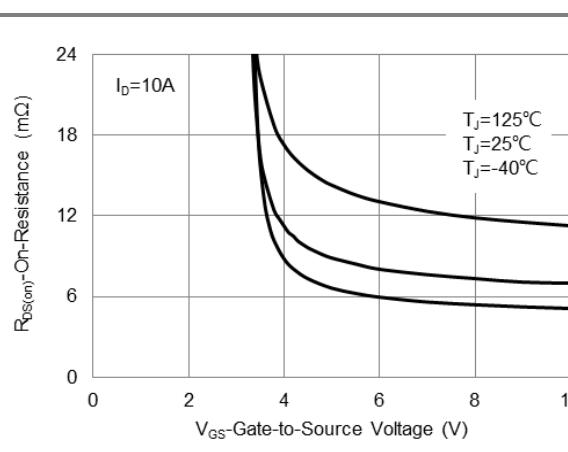


Fig.5 On-Resistance Variation with V_{Gs}

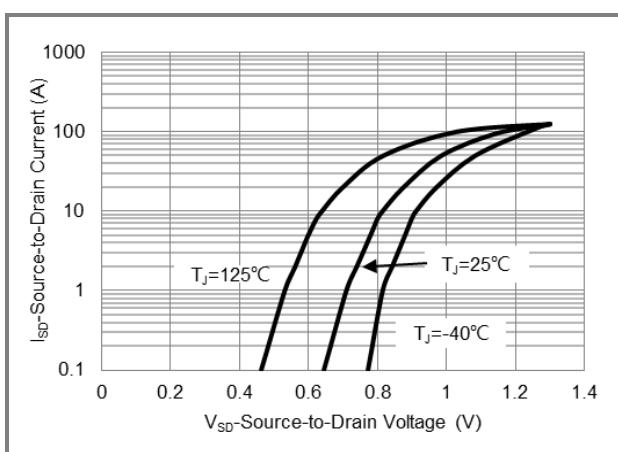


Fig.6 Source-Drain Diode Forward Voltage



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TYPICAL CHARACTERISTIC CURVES

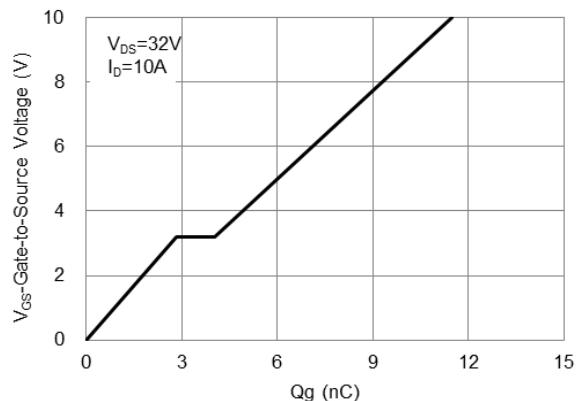


Fig.7 Gate-Charge Characteristics

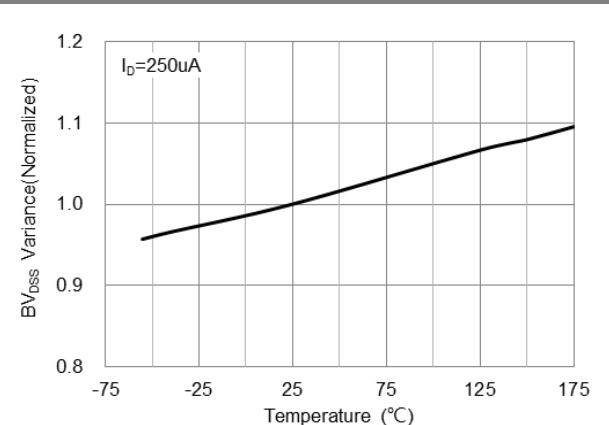


Fig.8 Breakdown Voltage Variation vs. Temperature

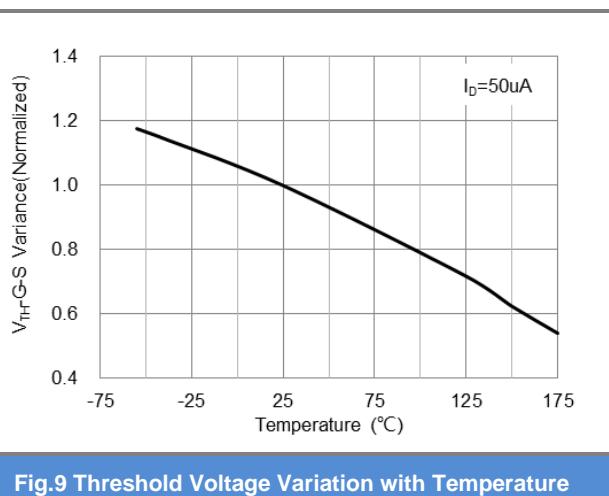


Fig.9 Threshold Voltage Variation with Temperature

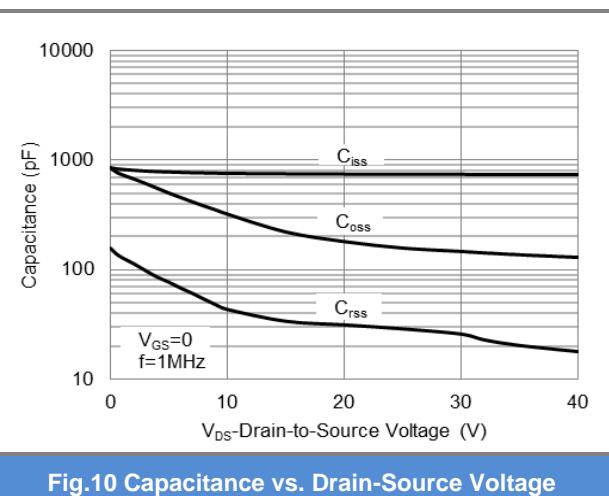


Fig.10 Capacitance vs. Drain-Source Voltage

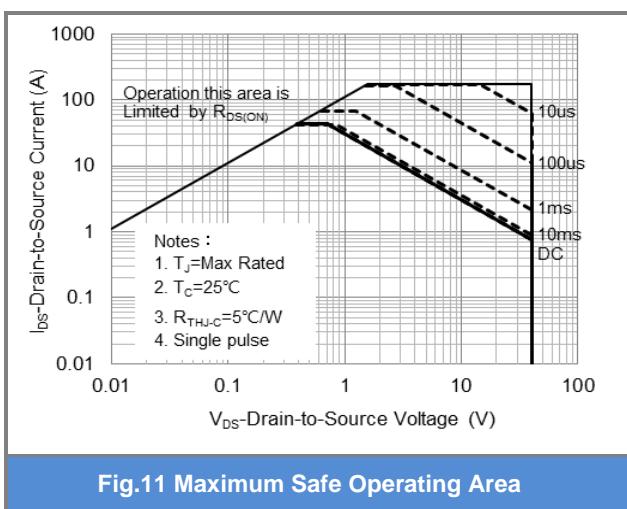


Fig.11 Maximum Safe Operating Area

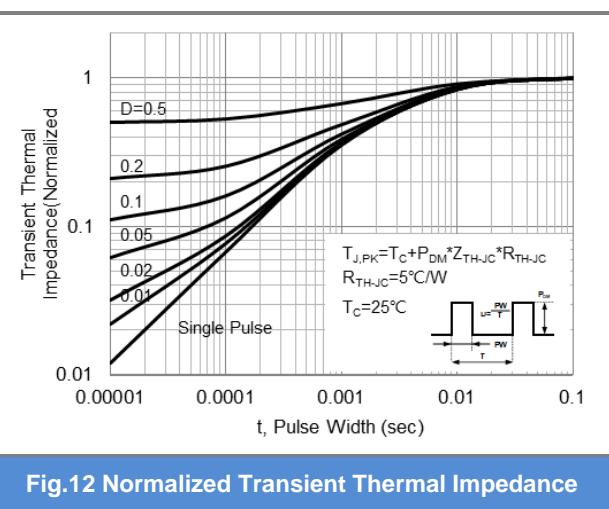


Fig.12 Normalized Transient Thermal Impedance

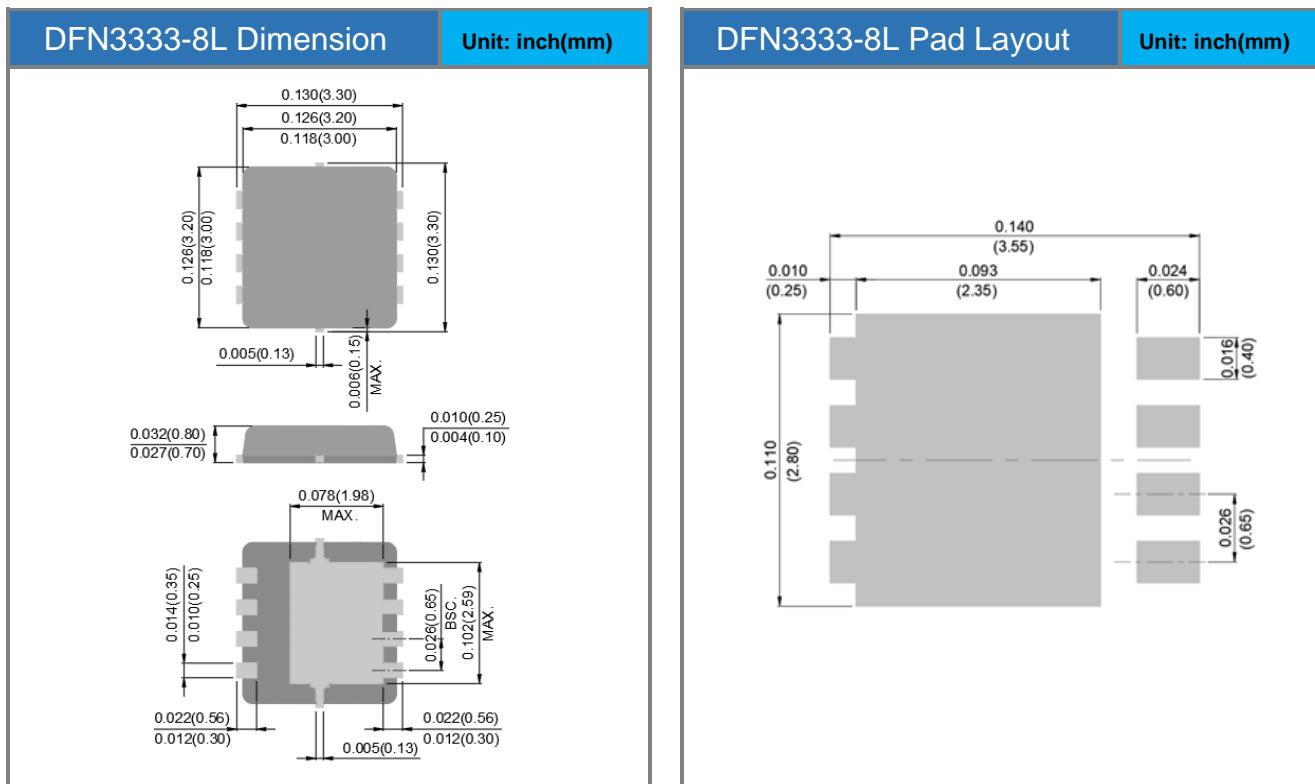


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Product and Packing Information

Part No.	Package Type	Packing Type	Marking
PJQ4548P-AU	DFN3333-8L	5K pcs / 13" reel	4548

Packaging Information & Mounting Pad Layout





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